

CMOS – HT65LBC184A Low-Power RS-485/RS-422

GENERAL DESCRIPTION

The HT65LBC184A is low-power transceivers for RS-485 and RS-422 communication. IC contains one driver and one receiver. The driver slew rates of the SN65LBC184 is not limited, allowing them to transmit up to 500Kbps. These transceivers draw between 120 μ A and 500 μ A of supply current when unloaded or fully loaded with disabled drivers. All parts operate from a single 5V supply. Drivers are short-circuit current limited and are protected against excessive power dissipation by thermal shutdown circuitry that places the driver outputs into a high-impedance state. The receiver input has a fail-safe feature that guarantees a logic-high output if the input is open circuit. The HT65LBC184A is designed for half-duplex applications.

FEATURES

- Extended ESD Protection for RS-485/RS-422 I/O Pins ± 15 kV Using Human Body Model
- Low Quiescent Current: 300 μ A
- 7V to +12V Common-Mode Input Voltage Range
- Three-State Outputs
- 30ns Propagation Delays, 5ns Skew
- Full-Duplex and Half-Duplex Versions Available
- Operate from a Single 5V Supply
- Allows up to 32 Transceivers on the Bus
- Data rate: 500Kbps
- Current-Limiting and Thermal Shutdown for Driver Overload Protection



DFN-8* D SUFFIX
HT65LBC184ARDZ



MSOP-8 M SUFFIX
HT65LBC184ARMZ



SOP-8 R SUFFIX
HT65LBC184ARZ

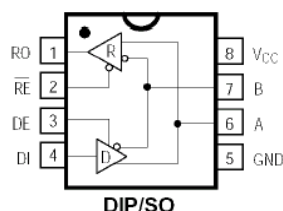


DIP-8* N SUFFIX
HT65LBC184ANZ

NOTE: suffix A is version, suffix R is roll tape, suffix Z environmental protection.

PIN CONFIGURATIONS

Pinning



ABSOLUTE MAXIMUM RATINGS

Supply Voltage (V_{CC}) 12V
 Control Input Voltage -0.5V to ($V_{CC} + 0.5$ V)
 Driver Input Voltage (DI) -0.5V to ($V_{CC} + 0.5$ V)
 Driver Output Voltage (A, B) -8V to +12.5V
 Receiver Input Voltage (A, B) -8V to +12.5V
 Receiver Output Voltage (RO) -0.5V to ($V_{CC} + 0.5$ V)

Continuous Power Dissipation
 8-Pin Plastic DIP (derate 9.09mW/ $^{\circ}$ C) 727mW
 8-Pin SO (derate 5.88mW/ $^{\circ}$ C) 471mW
 Operating Temperature Ranges -40 $^{\circ}$ C to +85 $^{\circ}$ C
 Storage Temperature Range -65 $^{\circ}$ C to +160 $^{\circ}$ C
 Lead Temperature (soldering, 10sec) +300 $^{\circ}$ C

DC ELECTRICAL CHARACTERISTICS

($V_{CC} = 5V \pm 5\%$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Differential Driver Output (no load)	VOD1 V		4.75			5.25
Differential Driver Output (with load)	VOD2	R = 50 Ω (RS-422)	2			V
		R = 27 Ω (RS-485), Figure 4	1.5		5	
Change in Magnitude of Driver Differential Output Voltage for Complementary Output States	ΔVOD	R = 27 Ω or 50 Ω , Figure 4			0.2	V
Driver Common-Mode Output Voltage	VOC	R = 27 Ω or 50 Ω , Figure 4			3	V
Change in Magnitude of Driver Common-Mode Output Voltage for Complementary Output States	ΔVOC	R = 27 Ω or 50 Ω , Figure 4			0.2	V
Input High Voltage	VIH	DE, DI, RE	2.0			V
Input Low Voltage	VIL	DE, DI, RE			0.8	V
Input Current	IIN1	DE, DI, RE			± 2	μA
Input Current (A, B)	IIN2	DE = 0V; VIN = 12V			1.0	mA
		VCC = 0V or 5.25V, VIN = -7V			-0.8	
Receiver Differential Threshold Voltage	VTH	-7V \leq V _{CM} \leq 12V	-0.2		0.2	V
Receiver Input Hysteresis	ΔVTH	VCM = 0V		70		mV
Receiver Output High Voltage	VOH	IO = -4mA, VID = 200mV	3.5			V
Receiver Output Low Voltage	VOL	IO = 4mA, VID = -200mV			0.4	V
Three-State (high impedance) Output Current at Receiver	IOZR	0.4V \leq VO \leq 2.4V			± 1	μA
Receiver Input Resistance	RIN	-7V \leq VCM \leq 12V				k Ω

DC ELECTRICAL CHARACTERISTICS (continued)

($V_{CC} = 5V \pm 5\%$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT S
No-Load Supply Current (Note 3)	ICC	DE = V _{CC}		500	900	μA
		RE = 0V or VCC		300	500	
		DE = 0V				
Driver Short-Circuit Current,						
	IOSD1	-7V \leq VO \leq 12V (Note 4)	35		250	mA
VO = High						
Driver Short-Circuit Current,						
	IOSD2	-7V \leq VO \leq 12V (Note 4)	35		250	mA
VO = Low						
Receiver Short-Circuit Current	IOSR	0V \leq VO \leq VCC	7		95	mA

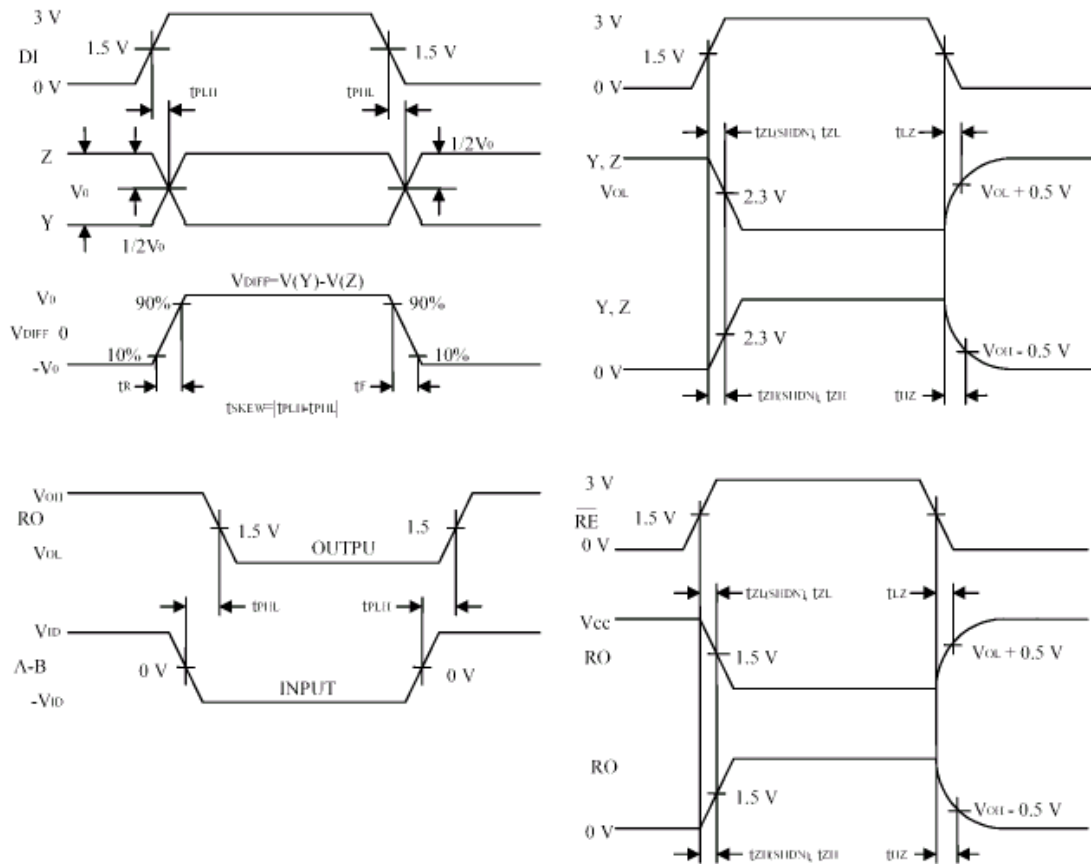
SWITCHING CHARACTERISTICS

($V_{CC} = 5V \pm 5\%$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Driver Input to Output	tPLH	RDIFF = 54Ω	10	30	60	ns
	tPHL	CL1 = CL2 = 100pF	10	30	60	
Driver Output Skew to Output	tSKEW	RDIFF = 54Ω, CL1 = CL2 = 100pF		5	10	ns
Driver Enable to Output High	tZH	CL = 100pF, S2 closed		40	70	ns
Driver Enable to Output Low	tZL	CL = 100pF, S1 closed		40	70	ns
Driver Disable Time from Low	tLZ	CL = 15pF, S1 closed		40	70	ns
Driver Disable Time from High	tHZ	CL = 15pF, S2 closed		40	70	ns
tPLH - tPHL Differential	tSKD	RDIFF = 54Ω		13		ns
Receiver Skew		CL1 = CL2 = 100pF				
Receiver Enable to Output Low	tZL	CRL = 15pF, S1 closed		20	50	ns
Receiver Enable to Output High	tZH	CRL = 15pF, S2 closed		20	50	ns
Receiver Disable Time from Low	tLZ	CRL = 15pF, S1 closed		20	50	ns
Receiver Disable Time from High	tHZ	CRL = 15pF, S2 closed		20	50	ns
Maximum Data Rate	fMAX		500			Kbps

Notes:

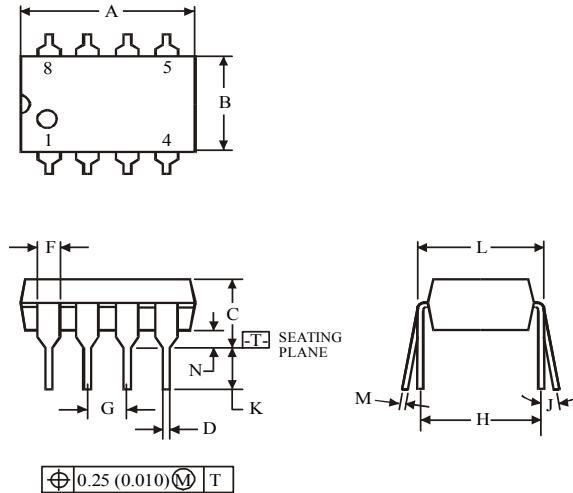
1. All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to device ground unless otherwise specified.
2. All typical specifications are given for $V_{CC} = 5V$ and $T_A = +25^\circ C$
3. Supply current specification is valid for loaded transmitters when $DE = 0V$
4. Applies to peak current. See *Typical Operating Characteristics*.



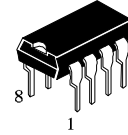
Transmission					Receipt			
Inputs			Outputs X		Inputs			Outputs
RE	DE	DI	Z	Y	RE	DE	A-B	RO
X	1	1	0	1	0	0	+0.2V	1
X	1	0	1	0	0	0	-0.2V	0
0	0	X	Z	Z	0	0	open	1
1	0	X	Z	Z	1	0	X	Z

X-don't care

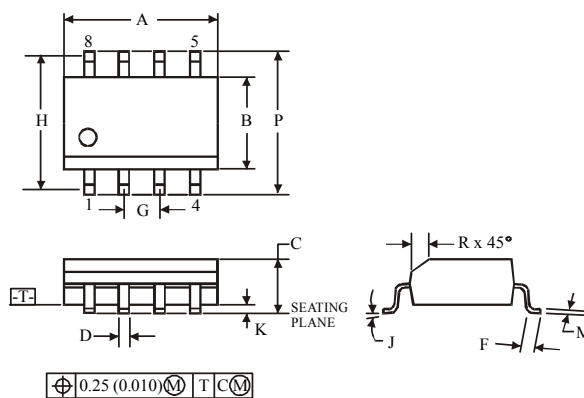
Z-high resistance

(DIP8)

NOTES:

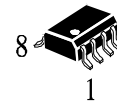
- Dimensions "A", "B" do not include mold flash or protrusions.
Maximum mold flash or protrusions 0.25 mm (0.010) per side.



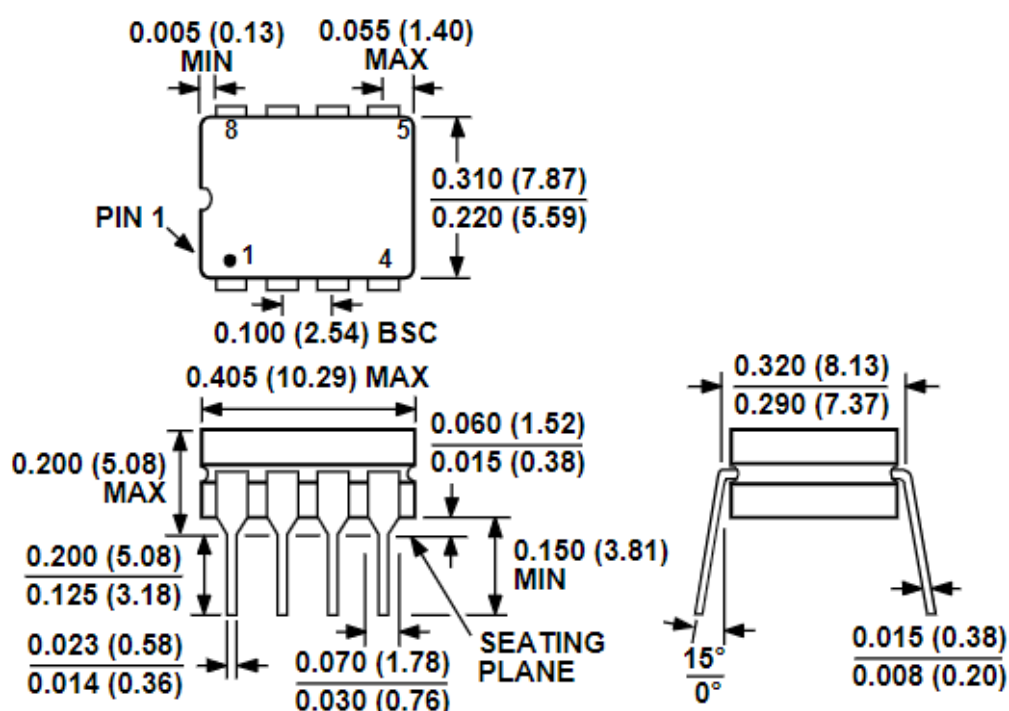
Symbol	Dimension, mm	
	MIN	MAX
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

(SOP8)

NOTES:

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.



Symbol	Dimension, mm	
	MIN	MAX
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

*Figure 51. 8-Lead Ceramic Dual In-Line Package [CERDIP] (Q-8)
Dimensions shown in inches and (millimeters)*